

Description

The μ A748 is a high performance monolithic operational amplifier constructed using the Fairchild Planar Epitaxial process. It is intended for a wide range of analog applications where tailoring of frequency characteristics is desirable. High common mode voltage range and absence of latch up make the μ A748 ideal for use as a voltage follower. The high gain and wide range of operating voltages provide superior performance in integrator, summing amplifier, and general feedback applications. The μ A748 is short circuit protected and has the same lead configuration as the popular μ A741 operational amplifier. Unity gain frequency compensation is achieved by means of a single 30 pF capacitor.

- **Short Circuit Protection**
- **Offset Voltage Null Capability**
- **Large Common Mode And Differential Voltage Ranges**
- **Low Power Consumption**
- **No Latch Up**

Absolute Maximum Ratings

Storage Temperature Range

Metal Can and Ceramic DIP	-65°C to +175°C
Molded DIP and SO-8	-65°C to +150°C

Operating Temperature Range

Extended (μ A748M)	-55°C to +125°C
Commercial (μ A748C)	0°C to +70°C

Lead Temperature

Metal Can and Ceramic DIP (soldering, 60 s)	300°C
Molded DIP and SO-8 (soldering, 10 s)	265°C

Internal Power Dissipation^{1, 2}

8L-Metal Can	1.00 W
8L-Molded DIP	0.93 W
8L-Ceramic DIP	1.30 W
SO-8	0.81 W

Supply Voltage

	± 22 V
--	------------

Differential Input Voltage

	± 30 V
--	------------

Input Voltage³

	± 15 V
--	------------

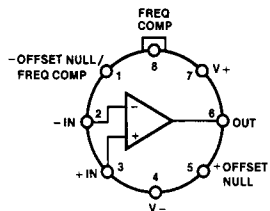
Output Short Circuit Duration⁴

	Indefinite
--	------------

Notes

1. $T_{J \text{ Max}}$ = 150°C for the Molded DIP and SO-8, and 175°C for the Metal Can and Ceramic DIP
2. Ratings apply to ambient temperature at 25°C. Above this temperature, derate the 8L-Metal Can at 6.7 mW/°C, the 8L-Molded DIP at 7.5 mW/°C, the 8L-Ceramic DIP at 8.7 mW/°C, and the SO-8 at 6.5 mW/°C.
3. For supply voltages less than ± 15 V, the absolute maximum input voltage is equal to the supply voltage.
4. Short circuit may be to ground or either supply. Rating applies to 125°C case temperature or +75°C ambient temperature.

Connection Diagram 8-Lead Metal Package (Top View)



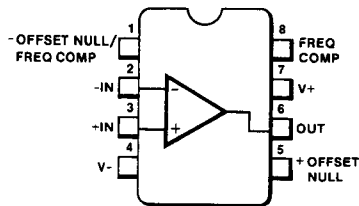
CD00511F

Lead 4 connected to case.

Order Information

Device Code	Package Code	Package Description
μ A748HM	5W	Metal
μ A748HC	5W	Metal

Connection Diagram 8-Lead DIP and SO-8 Package (Top View)

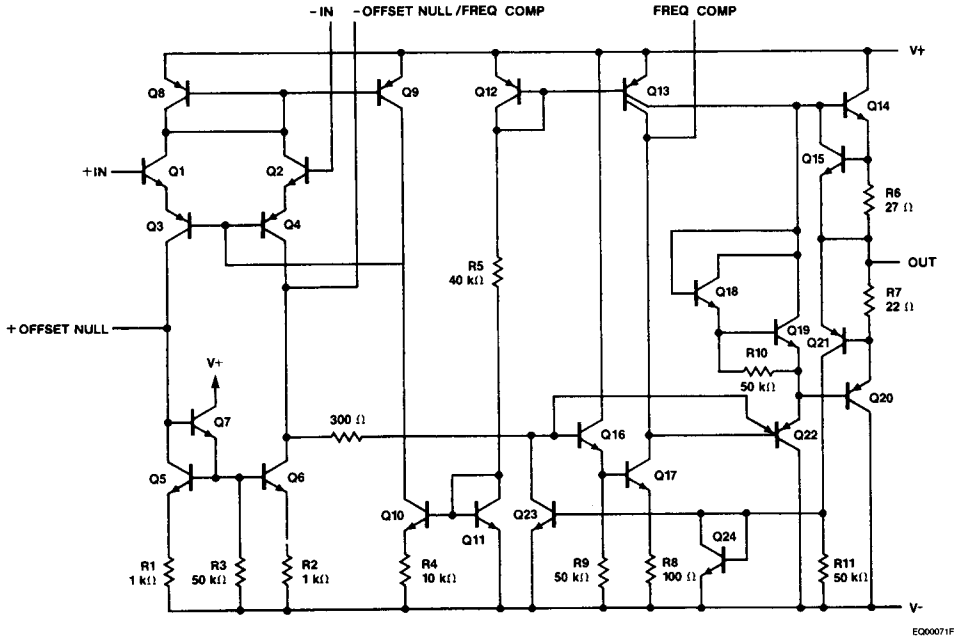


CD00541F

Order Information

Device Code	Package Code	Package Description
μ A748RC	6T	Ceramic DIP
μ A748SC	KC	Molded Surface Mount
μ A748TC	9T	Molded DIP

Equivalent Circuit



μA748

μA748

Electrical Characteristics $T_A = 25^\circ\text{C}$, $V_{CC} = \pm 15\text{ V}$, $C_C = 30\text{ pF}$, unless otherwise specified.

Symbol	Characteristic	Condition	Min	Typ	Max	Unit
V_{IO}	Input Offset Voltage	$R_S \leq 10\text{ k}\Omega$		1.0	5.0	mV
$V_{IO\text{ adj}}$	Input Offset Voltage Adjustment Range			± 15		mV
I_{IO}	Input Offset Current			20	200	nA
I_{IB}	Input Bias Current			80	500	nA
Z_I	Input Impedance		0.3	2.0		M Ω
I_{CC}	Supply Current			1.9	2.8	mA
P_c	Power Consumption			60	85	mW
I_{OS}	Output Short Circuit Current			25		mA
A_{VS}	Large Signal Voltage Gain	$R_L \geq 2.0\text{ k}\Omega$, $V_O = \pm 10\text{ V}$	50	150		V/mV
TR	Transient Response	Rise time	$V_I = 20\text{ mV}$, $C_C = 30\text{ pF}$, $R_L = 2.0\text{ k}\Omega$, $C_L = 100\text{ pF}$, $A_V = 1.0$	0.3		μs
		Overshoot		5.0		%
SR	Slew Rate	$R_L = 2.0\text{ k}\Omega$, $A_V = 1.0$		0.5		V/ μs
		$R_L = 2.0\text{ k}\Omega$, $C_C = 3.5\text{ pF}$, $A_V = 10$		5.5		

The following specifications apply for $-55^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$

V_{IO}	Input Offset Voltage	$R_S \leq 10\text{ k}\Omega$		1.0	6.0	mV
I_{IO}	Input Offset Current	$T_A = T_{A\text{ Max}}$		10	200	nA
		$T_A = T_{A\text{ Min}}$		50	500	
I_{IB}	Input Bias Current	$T_A = T_{A\text{ Max}}$		0.03	0.5	μA
		$T_A = T_{A\text{ Min}}$		0.3	1.5	
I_{CC}	Supply Current	$T_A = T_{A\text{ Max}}$		1.5	2.5	mA
		$T_A = T_{A\text{ Min}}$		2.0	3.3	
P_c	Power Consumption	$T_A = T_{A\text{ Max}}$		45	75	mW
		$T_A = T_{A\text{ Min}}$		60	100	
CMR	Common Mode Rejection	$R_S \leq 10\text{ k}\Omega$	70	90		dB
V_{IR}	Input Voltage Range		± 12	± 13		V
PSRR	Power Supply Rejection Ratio	$R_S \leq 10\text{ k}\Omega$		30	150	$\mu\text{V/V}$
A_{VS}	Large Signal Voltage Gain	$R_L \geq 2.0\text{ k}\Omega$, $V_O = \pm 10\text{ V}$	25			V/mV
V_{OP}	Output Swing	$R_L = 10\text{ k}\Omega$	± 12	± 14		V
		$R_L = 2.0\text{ k}\Omega$	± 10	± 13		

μA748C

Electrical Characteristics $T_A = 25^\circ\text{C}$, $V_{CC} = \pm 15\text{ V}$, $C_C = 30\text{ pF}$, unless otherwise specified.

Symbol	Characteristic	Condition	Min	Typ	Max	Unit
V_{IO}	Input Offset Voltage	$R_S \leq 10\text{ k}\Omega$		2.0	6.0	mV
I_{IO}	Input Offset Current			20	200	nA
I_{IB}	Input Bias Current			80	500	nA
Z_I	Input Impedance		0.3	2.0		M Ω
I_{CC}	Supply Current			1.9	2.8	mA
P_c	Power Consumption			60	85	mW
I_{OS}	Output Short Circuit Current			25		mA
A_{VS}	Large Signal Voltage Gain	$R_L \geq 2.0\text{ k}\Omega$, $V_O = \pm 10\text{ V}$	20	150		V/mV
TR	Transient Response	Rise time	$V_I = 20\text{ mV}$, $C_C = 30\text{ pF}$, $R_L = 2.0\text{ k}\Omega$, $C_L = 100\text{ pF}$, $A_V = 1.0$	0.3		μs
		Overshoot		5.0		%
SR	Slew Rate	$R_L = 2.0\text{ k}\Omega$, $A_V = 1.0$		0.5		V/ μs

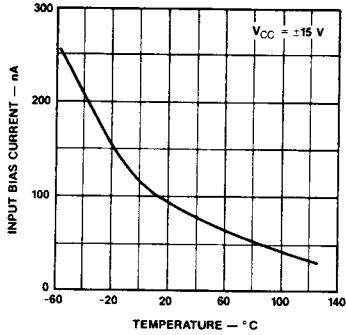
The following specifications apply for $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$

V_{IO}	Input Offset Voltage	$R_S \leq 10\text{ k}\Omega$		2.0	7.5	mV
I_{IO}	Input Offset Current	$T_A = T_{A\text{ Max}}$			300	nA
		$T_A = T_{A\text{ Min}}$			800	μA
I_{CC}	Supply Current	$T_A = T_{A\text{ Max}}$		1.5	2.5	mA
		$T_A = T_{A\text{ Min}}$		2.0	3.3	
P_c	Power Consumption	$T_A = T_{A\text{ Max}}$		45	75	mW
		$T_A = T_{A\text{ Min}}$		60	100	
CMR	Common Mode Rejection	$R_S \leq 10\text{ k}\Omega$	70	90		dB
V_{IR}	Input Voltage Range		± 12	± 13		V
PSRR	Power Supply Rejection Ratio	$R_S \leq 10\text{ k}\Omega$		30	150	$\mu\text{V/V}$
A_{VS}	Large Signal Voltage Gain	$R_L \geq 2.0\text{ k}\Omega$, $V_O = \pm 10\text{ V}$	15			V/mV
V_{OP}	Output Voltage Swing	$R_L = 10\text{ k}\Omega$	± 12	± 14		V
		$R_L = 2.0\text{ k}\Omega$	± 10	± 13		

7

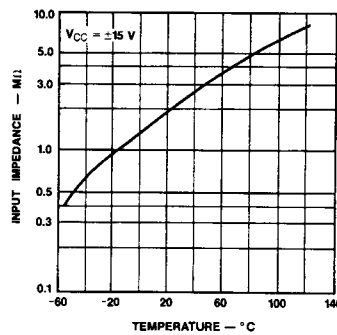
Typical Performance Curves for μA748

Input Bias Current vs Temperature



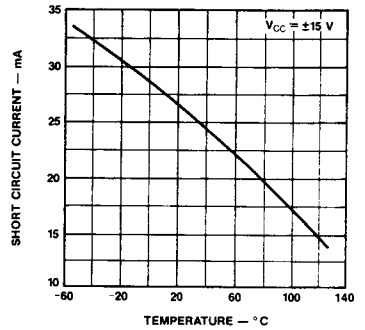
PC03081F

Input Impedance vs Temperature



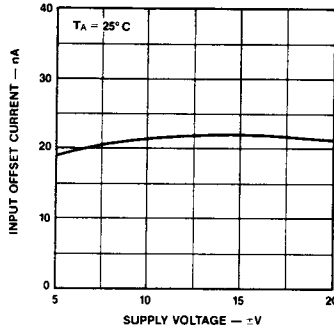
PC03091F

Short Circuit Current vs Temperature



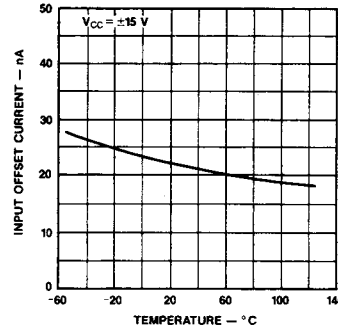
PC03100F

Input Offset Current vs Supply Voltage



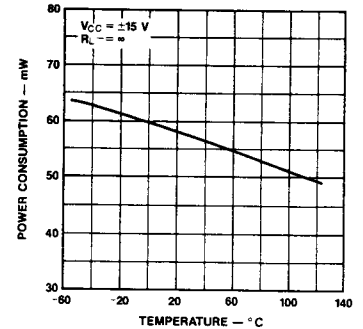
PC03110F

Input Offset Current vs Temperature



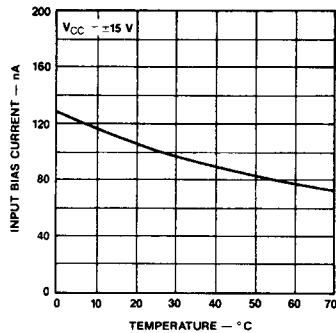
PC03120F

Power Consumption vs Temperature



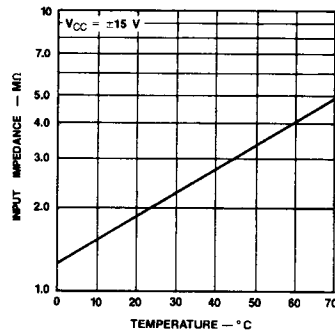
PC03130F

Input Bias Current vs Temperature for μA748C



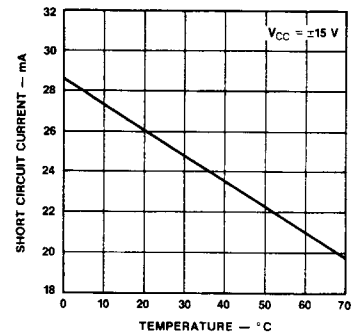
PC03141F

Input Impedance vs Temperature for μA748C



PC03151F

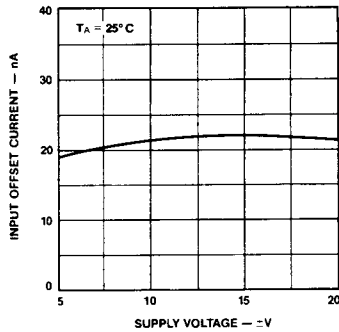
Short Circuit Current vs Temperature for μA748C



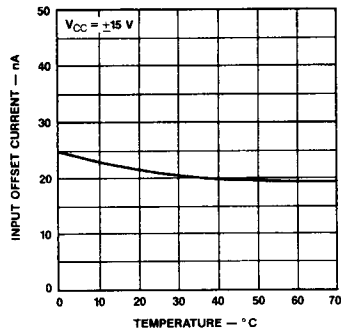
PC03161F

Typical Performance Curves for μA748 and μA748C (Cont.)

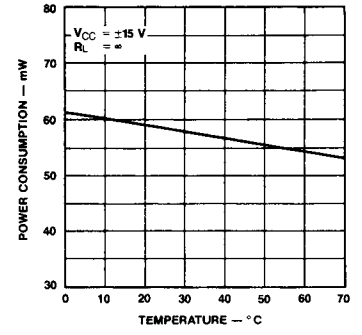
Input Offset Current vs Supply Voltage for μA748C



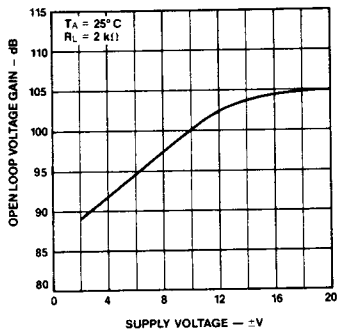
Input Offset Current vs Temperature for μA748C



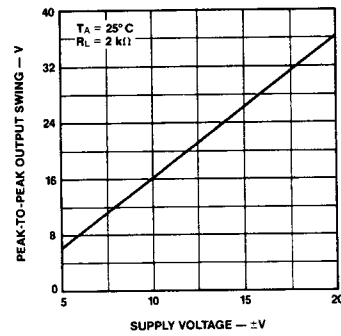
Power Consumption vs Temperature for μA748C



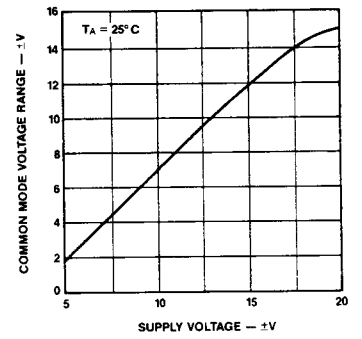
Voltage Gain vs Supply Voltage



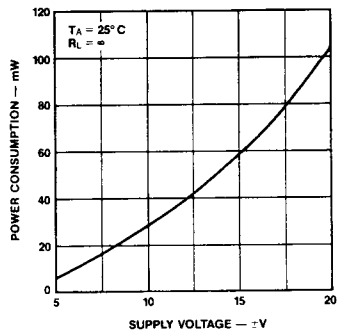
Output Voltage Swing vs Supply Voltage



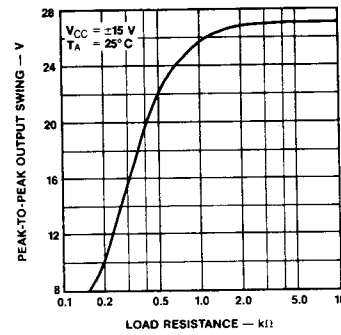
Input Common Mode Voltage Range vs Supply Voltage



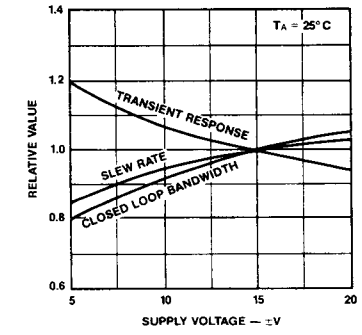
Power Consumption vs Supply Voltage



Output Voltage Swing vs Load Resistance



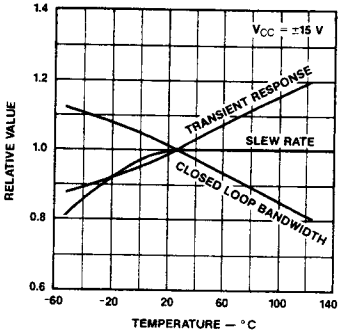
Frequency Characteristics vs Supply Voltage



7

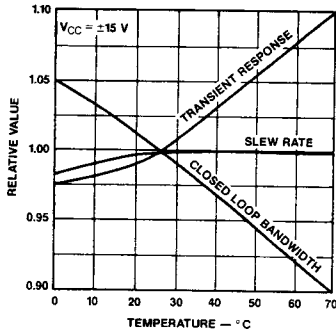
Typical Performance Curves for μA748 and μA748C (Cont.)

Frequency Characteristics vs Temperature for μA748



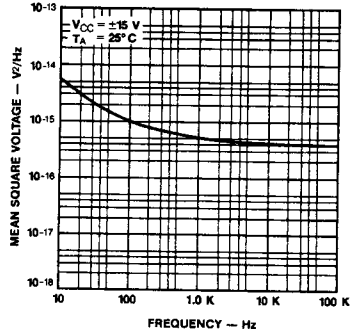
PC03270F

Frequency Characteristics vs Temperature for μA748C



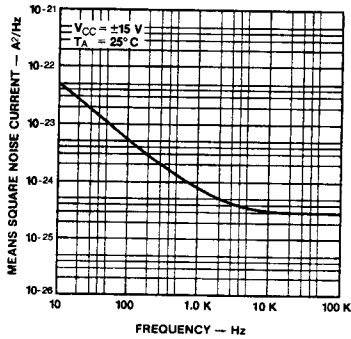
PC03260F

Input Noise Voltage vs Frequency



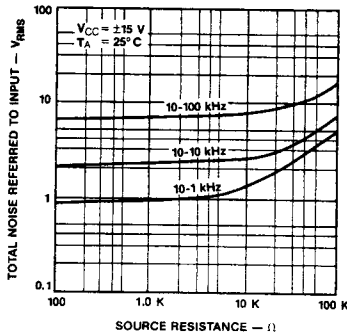
PC03281F

Input Noise Current vs Frequency



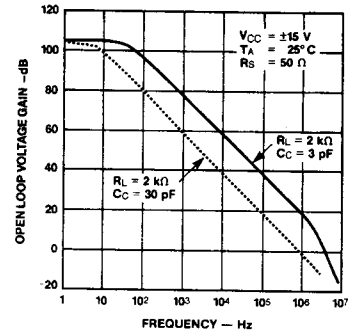
PC03291F

Broadband Noise for Various Bandwidths



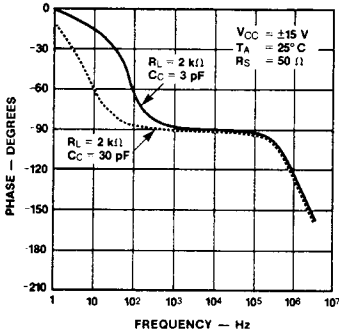
PC03301F

Open Loop Frequency Response for RL = 2 kΩ



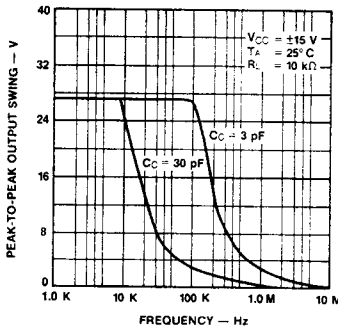
PC03311F

Open Loop Phase Response vs Frequency



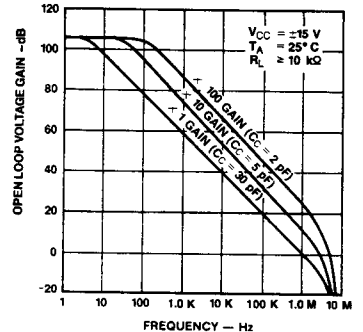
PC03321F

Output Voltage Swing vs Frequency



PC03331F

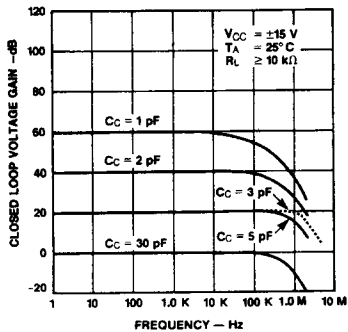
Open Loop Frequency Response for RL ≥ 10 kΩ



PC03341F

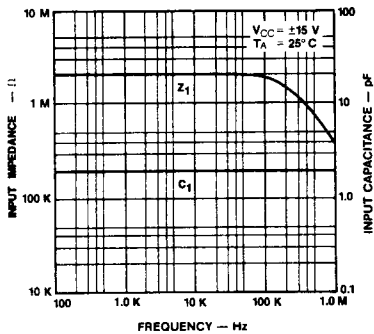
Typical Performance Curves for μA748 and μA748C (Cont.)

Frequency Response for Various Closed Loop Gains



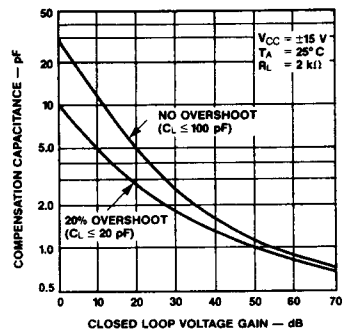
PC03351F

Input Impedance and Input Capacitance vs Frequency



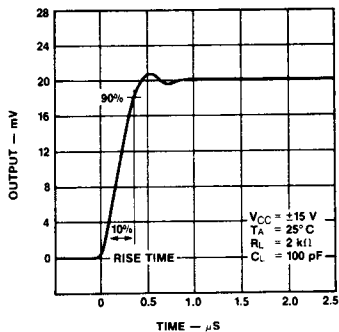
PC03371F

Compensation Capacitance vs Closed Loop Voltage Gain



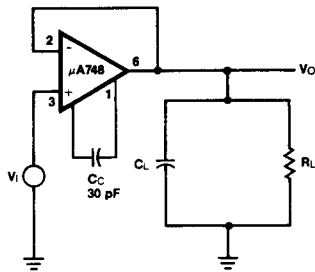
PC03380F

Voltage Follower Transient Response (Gain of 1)



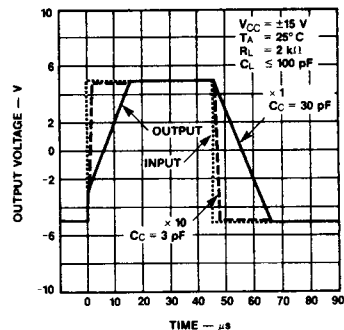
PC03391F

Transient Response Test Circuit



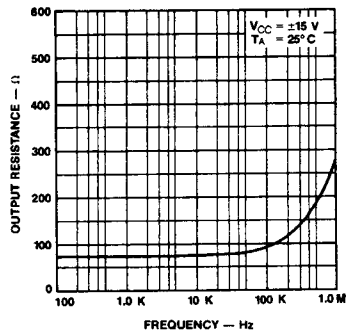
TC00010F

Voltage Follower Large Signal Pulse Response



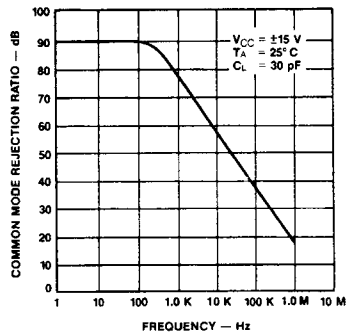
PC03381F

Output Resistance vs Frequency



PC03391F

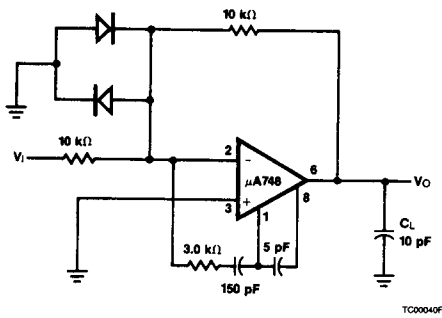
Common Mode Rejection Ratio vs Frequency



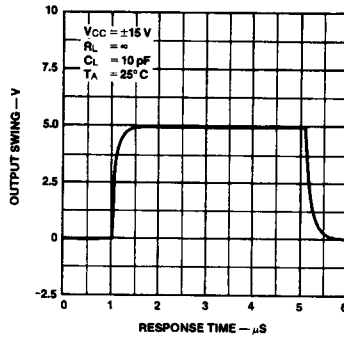
PC03401F

Test Circuits

Feed Forward Compensation

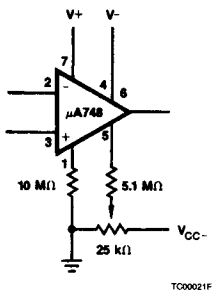


Large Signal Feed Forward Transient Response

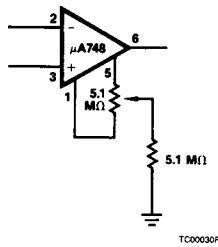


Voltage Offset Null Circuit

Suggested

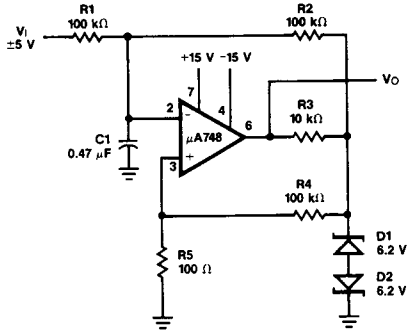


Alternate



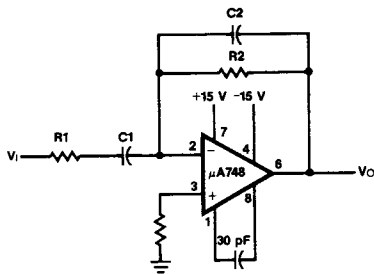
Typical Applications

Pulse Width Modulator



AF00500F

Practical Differentiator



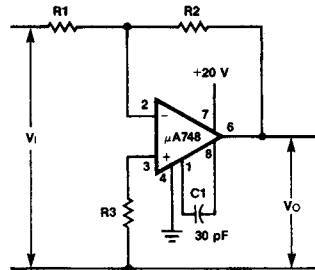
AF00511F

$$f_c = \frac{1}{2\pi R_2 C_1}$$

$$f_h = \frac{1}{2\pi R_1 C_1} = \frac{1}{2\pi R_2 C_2}$$

$$f_c < f_h < f_{\text{unity gain}}$$

Circuit for Operating the μA748 Without a Negative Supply



TC00051F